

TOSHIBA

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Toshiba Memory America, Inc.

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Image may be representation. See specifications for product details.

TC58CVG2S0HQAIE

Part Number:	TC58CVG2S0HQAIE
Manufacturer/Brand:	Toshiba Memory America, Inc.
Product description	IC FLASH 4G SPI 104MHZ 16SOP
Datasheets:	 TC58CVG2S0HQAIE.pdf
RoHs Status	 Lead free / RoHS Compliant
Stock Condition	5981 pcs stock
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

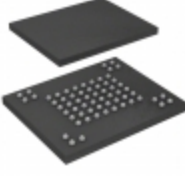
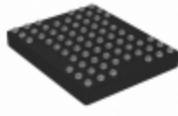
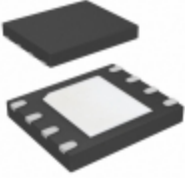
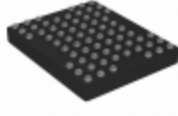
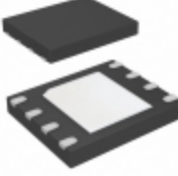
Specifications of TC58CVG2S0HQAIE

PART NUMBER	TC58CVG2S0HQAIE
MANUFACTURER	Toshiba Memory America, Inc.
DESCRIPTION	IC FLASH 4G SPI 104MHZ 16SOP
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
QUANTITY AVAILABLE	5981 pcs
DATA SHEET	 TC58CVG2S0HQAIE.pdf
WRITE CYCLE TIME - WORD, PAGE	-
VOLTAGE - SUPPLY	2.7 V ~ 3.6 V
TECHNOLOGY	FLASH - NAND (SLC)
SUPPLIER DEVICE PACKAGE	16-SOP
SERIES	-
PACKAGING	Tray
PACKAGE / CASE	16-SOIC (0.295", 7.50mm Width)
OTHER NAMES	TC58CVG2S0HQAIEY0J TC58CVG2S0HQAIEYCJ
OPERATING TEMPERATURE	-40°C ~ 85°C (TA)
MOUNTING TYPE	Surface Mount
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Non-Volatile
MEMORY SIZE	4Gb (512M x 8)
MEMORY INTERFACE	SPI - Quad I/O
MEMORY FORMAT	FLASH
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	FLASH - NAND (SLC) Memory IC 4Gb (512M x 8) SPI - Quad I/O 104MHz 280µs 16-SOP
CLOCK FREQUENCY	104MHz
ACCESS TIME	280µs

Related Tags

Toshiba Memory America, Inc. TC58CVG2S0HQAIE	TC58CVG2S0HQAIE Distributor	TC58CVG2S0HQAIE Supplier
TC58CVG2S0HQAIE Price	TC58CVG2S0HQAIE Pictures	TC58CVG2S0HQAIE Image
TC58CVG2S0HQAIE PDF Datasheet	TC58CVG2S0HQAIE Download Datasheet	TC58CVG2S0HQAIE Datasheet
TC58CVG2S0HQAIE Stock	Buy TC58CVG2S0HQAIE	Buy Toshiba Memory America, Inc. TC58CVG2S0HQAIE
Toshiba Memory America, Inc. TC58CVG2S0HQAIE	Toshiba Memory America, Inc. Supplier	Toshiba Memory America, Inc. Distributor
Toshiba Memory America, Inc. TC58CVG2S0HQAIE		

Related Products

 TC58CYG0S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 1GB SERIAL NAND 24NM WSON 1.8V In stock: 25461 pcs RFQ	 TC58BYG1S3HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: 2GB SLC NAND BGA 24NM I TEMP (EE) In stock: 21534 pcs RFQ
 TC58CYG2S0HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 4GB SERIAL NAND 24NM WSON 1.8V In stock: 20760 pcs RFQ	 TC58CVG1S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 2GB SERIAL NAND 24NM WSON 3.3V In stock: 20038 pcs RFQ
 TC58NVG0S3HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G PARALLEL 63TFBGA In stock: 28717 pcs RFQ	 TC58BYG2S0HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G PARALLEL 67VFBGA In stock: 16088 pcs RFQ
 TC58CYG0S3HQAIE Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G SPI 104MHZ 16SOP In stock: 4718 pcs RFQ	 TC58CYG1S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 2GB SERIAL NAND 24NM WSON 1.8V In stock: 20305 pcs RFQ
 TC58CVG0S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G SPI 104MHZ 8WSON In stock: 21309 pcs RFQ	 TC58BYG1S3HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 2G PARALLEL 67VFBGA In stock: 24557 pcs RFQ
 TC58CVG0S3HQAIE Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G SPI 104MHZ 16SOP In stock: 6477 pcs RFQ	 TC58CVG2S0HRAIG Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G SPI 104MHZ 8WSON In stock: 16041 pcs RFQ